Transistors

Genera purpose amplification(–12V, –1.5A) 2SB1732

Application

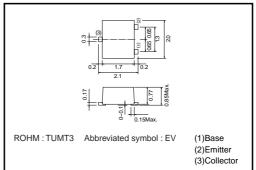
Low frequency amplifier Driver

● Features

- 1) A collector current is large.
- 2) Collector saturation voltage is low.

 $V_{CE(sat)} \leq -200 mV$ at Ic = $-500 mA / I_B = -25 mA$

●External dimensions (Unit: mm)



● Absolute maximum ratings (Ta=25°C)

| Parameter | Symbol | Limits | Unit |
|------------------------------|--------|-------------|------------------|
| Collector-base voltage | Vсво | -15 | V |
| Collector-emitter voltage | Vceo | -12 | V |
| Emitter-base voltage | Vево | -6 | V |
| Collector current | Ic | -1.5 | Α |
| Collector current | ICP | -3 | A*1 |
| Power dissipation | Pc | 400 | mW ^{*2} |
| Junction temperature | Tj | 150 | °C |
| Range of storage temperature | Tstg | -55 to +150 | °C |

^{*1}Single pulse, Pw=1ms

Packaging specifications

| | Package | Taping |
|---------|------------------------------|--------|
| Туре | Code | TL |
| | Basic ordering unit (pieces) | 3000 |
| 2SB1732 | | 0 |

●Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|--------------------------------------|----------|------|------|------|------|-------------------------------|
| Collector-base breakdown voltage | ВУсво | -15 | _ | _ | V | Ic=-10μA |
| Collector-emitter breakdown voltage | BVceo | -12 | _ | _ | V | Ic=-1mA |
| Emitter-base breakdown voltage | ВVево | -6 | _ | _ | V | I _E =-10μA |
| Collector cutoff current | Ісво | _ | _ | -100 | nA | Vcb=-15V |
| Emitter cutoff current | ІЕВО | _ | _ | -100 | nA | V _{EB} =-6V |
| Collector-emitter saturation voltage | VCE(sat) | _ | -85 | -200 | mV | Ic=-500mA, Iв=-25mA |
| DC current gain | hfe | 270 | _ | 680 | - | Vce=-2V, Ic=-200mA * |
| Transition frequency | f⊤ | _ | 400 | _ | MHz | Vce=-2V, Ie=200mA, f=100MHz * |
| Corrector output capacitance | Cob | _ | 12 | _ | pF | Vcb=-10V, Ie=0A, f=1MHz |

^{*} Pulsed

^{*2}Each Terhinal Mounted on a Recommended Land

Transistors

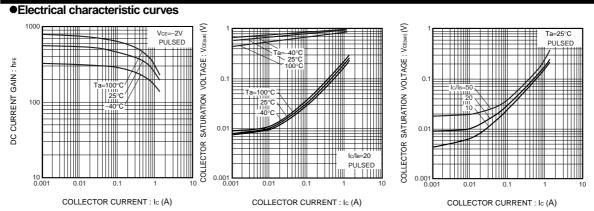


Fig.1 DC current gain vs. collector current

Fig.2 Collector-emitter saturation voltage vs.collector current

Fig.3 Base-emitter saturation voltage vs.collector current

Fig.4 Collector-emitter saturation voltage vs. collector current

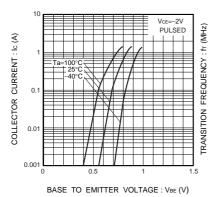


Fig.5 Grounded emitter propagation characteristics

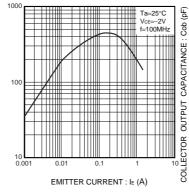
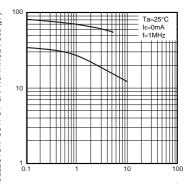


Fig.6 Gain bandwidth product vs. emitter current



COLLECTOR TO BASE VOLTAGE: VcB (V)

Fig.7 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

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